

## Requirement :

1. Normal mode, IDD >> 1mA to 150mA
2. Sleep mode IDD >> 1uA to 100uA

### Optional Components for Proto Board >>

1. Schottky Diodes D8, D9, D10 (drop 0.3V) can be assembled and remove R116, R149 to eliminate the DS1314 quiscent current error in SRAM current reading. Drawback will be the additional 0.3V drop in VDD to SRAM in normal mode and battery mode.

2. Make R53 = 0.68 Ohm . Compnestate for FET ON resistenace (30 mOhm apprx. Will have device to device variation). If this error is accepable for application, no need to use 2nd Instrumentation Amp U20. Also, we can use one channel pin compatiabile ADC - ADS1014

